OPB950Z

Obsolete (OPB951)

Features:

- Dual channel outputs for Quadrature Output
- Open collector inverter outputs
- 0.010" (0.254 mm) sensor apertures for high resolution
- Snap mount





Description:

The OPB950Z consists of an infrared Light Emitting Diode (LED) and a monolithic integrated circuit which incorporates two independent photodiodes, linear amplifiers, Schmitt trigger circuits and output transistors. It features a dual open-collector output that is compatible with TTL/LSTTL and can drive up to 8 TTL loads.

Applications include linear and rotary encoders with high resolution provided by internal 0.010" (0.254 mm) apertures located in front of each Photologic® sensor on 0.040" (1.02 mm) center line spacing.

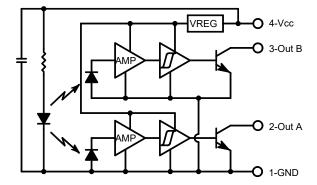
Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Mechanical switch replacement
- Speed and direction indication
- Mechanical limit indication
- Rotary encoders
- Edge sensing
- Sliding Door Automotive and Liftgate applications

Ordering Information										
Part Number			Slot Width / Depth	Aperture Emitter/ Sensor	Connector					
OPB950Z					Wellpex					
OPB951 Obsolete	890 nm	Dual TTL	0.200" / 0.350"	0.05" / 0.01"	C25002WS-04-LF					

OPB950Z





RoHS

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Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +85° C
Input Diode	
Forward DC Current	50 mA
Reverse DC Voltage	2.0 V
Power Dissipation	100 mW
Output Photologic®	
Supply Voltage, V _{CC}	5.5 V
Voltage at Output	16 V
Power Dissipation	200 mW
Sinking Output Current	40 mA

Electrical Characteristics ($T_A = 25^{\circ}$ C and $V_{CC} = +5$ Volts unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
V _{cc}	Operating Supply Voltage		-	5.5	V	-
E _{ET} (+)/E _{ET} (-)	Hysteresis Ratio	1.1	1.5	2	-	-
МАТСН	CH Channel Match $E_{ET}^{(+A)}/E_{ET}^{(+B)}$		1	1.5	-	-
I _{CCL}	Supply Current, Both Outputs Low (LED On, No Target)	-	8.5	12	mA	$E_E = 0.5 \text{ mW/cm}^2 \text{ (no load on output)}$
I _{ссн}	Supply Current, Both Outputs High (LED Off)	-	3.5	6	mA	E _E = 0 mW/cm ² (no load on output)
I _{CCM}	Supply Current, Mixed Output States (one high, one low)	-	6	-	mA	$E_E = 0 \text{ mW/cm}^2 \text{ and } 0.5 \text{ mW/cm}^2$
l _{oh}	High Level Output Current	-	1	30	μΑ	$E_E = 0 \text{ mW/cm}^2$, $V_{OH} = 16 \text{ V}$
V _{OL}	Low Level Output Voltage	-	0.21	0.4	V	$E_E = 0 \text{ mW/cm}^2$, $I_{OL} = 12.8 \text{ mA}$
T _{PHL} T _{PLH}	Propagation Delay Output High to Low Output Low to High	-	2 10	1	μs μs	V_{CC} = 5 V, R_L = 360 Ω E_E = 0 or 0.5 mW/cm ² , f = 10 kHz, D.C. = 50%
t _r t _f	Output Rise Time Output Fall Time	-	20 15	1	ns ns	-

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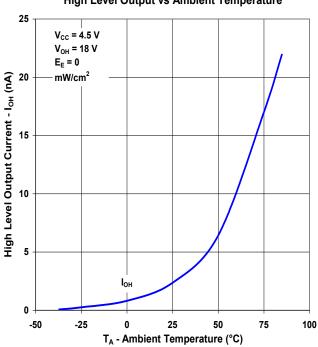
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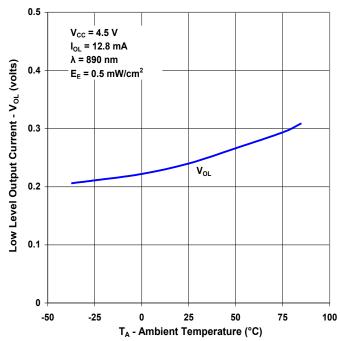


Performance

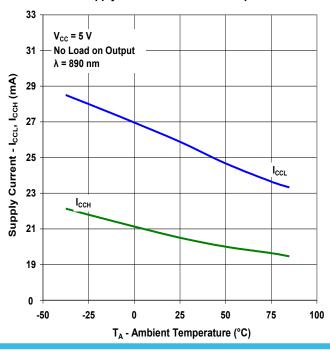
High Level Output vs Ambient Temperature



Low Level Output vs Ambient Temperature



Supply Current vs Ambient Temperature



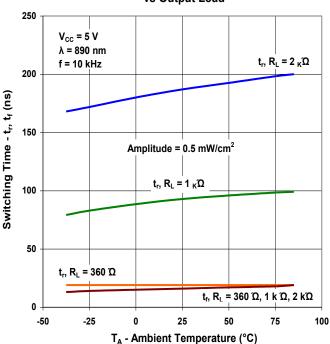
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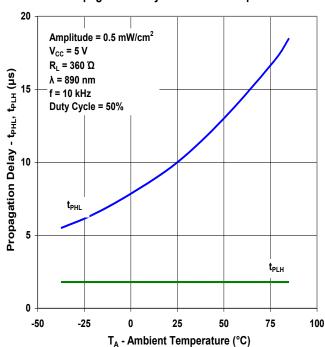


Performance

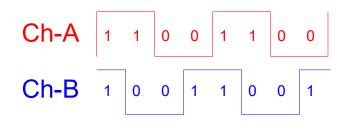
Rise and Fall Time vs Ambient Temperature vs Output Load



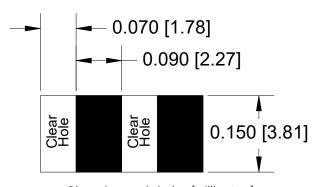
Propagation Delay vs Ambient Temperature



Sensor Output(s)



Ideal Target Size & Spacing For Linear or Circular Targets



Dimensions are in inches [millimeters]

Please consult OPTEK for target design and sensor location relative to the target.

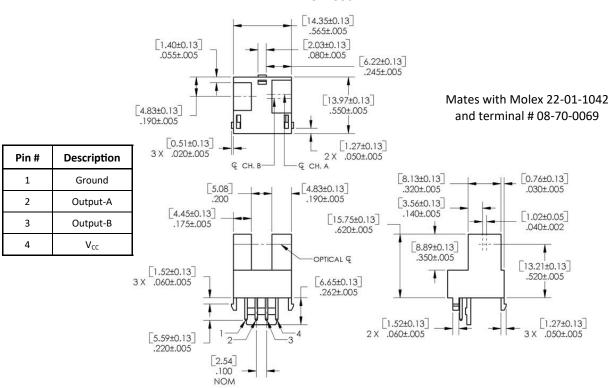
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Packaging

OPB950Z



Mouser Electronics

Authorized Distributor

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TT Electronics:

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